

Institut für Mikroelektronik Stuttgart



Nanopatterning @ IMS CHIPS

BEAMeeting Stuttgart 2024

10.04.2024

Julian Hartbaum



Institut für Mikroelektronik Stuttgart

Civil law foundation

Member of Innovationsallianz Baden-Württemberg

- **Director**

Prof. Dr. Joachim N. Burghartz

- **Established**

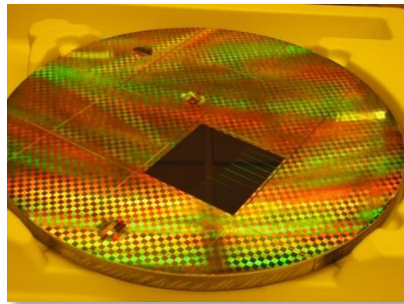
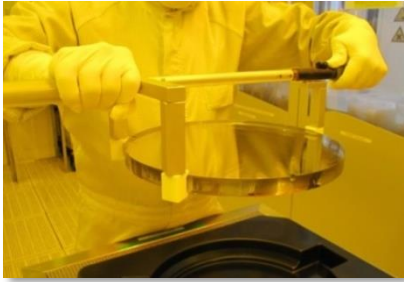
1983 in the state of Baden-Württemberg

- **Today**

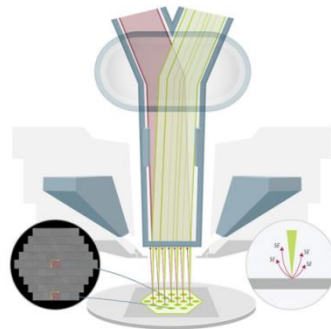
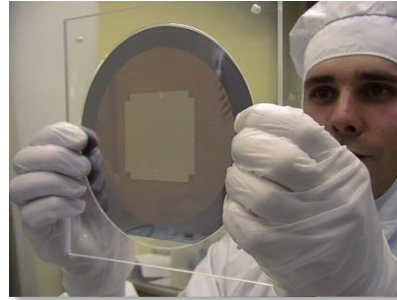
100+ employees

16.3 million € operating budget

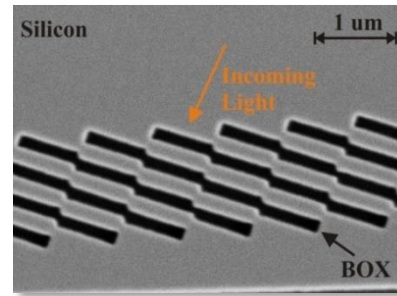
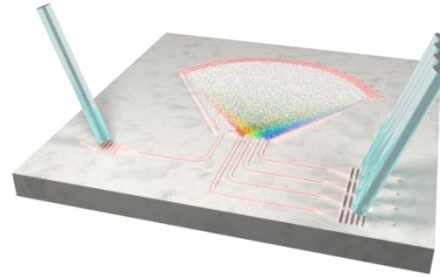
Optical Components



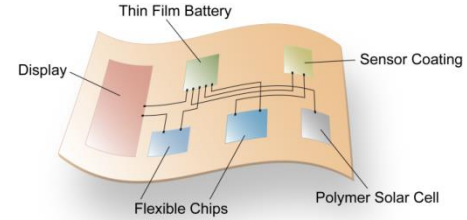
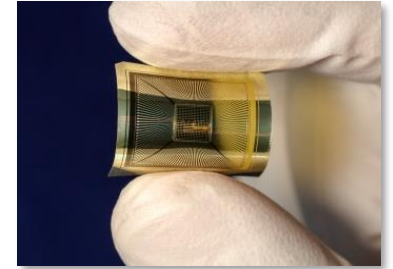
MEMS



Si Photonics



Flexible Electronic





- FPA-3000 i5a
- Die size: 22mm x 25mm
- Through Silicon alignment



- HIMT VPG400

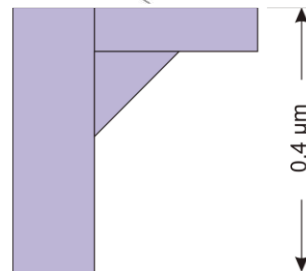
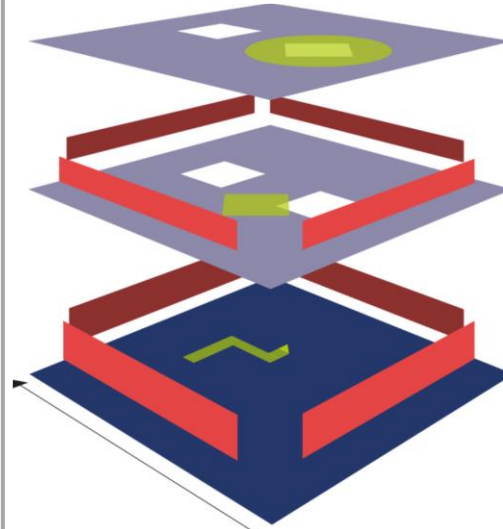


- HIMT ULTRA

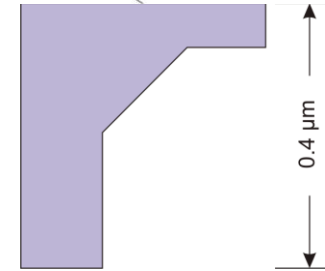
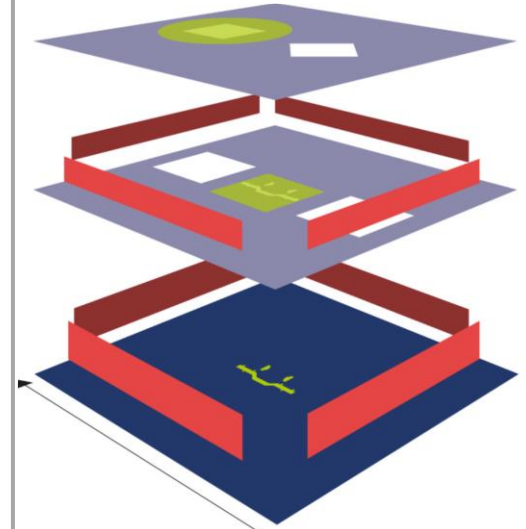


- 100-, 150- & 200-mm Wafer; 6''-masks
- Cell Projection

• Variable Shaped



• Cell Projection



E-Beam Patterning: Vistec SB4050





- Wafer 150, 200, 300 mm
- Masks 6025, 9035
- Customized substrates up to \varnothing 450 mm



- Variable shape beam
- Air bearing stage
- Tight climate control

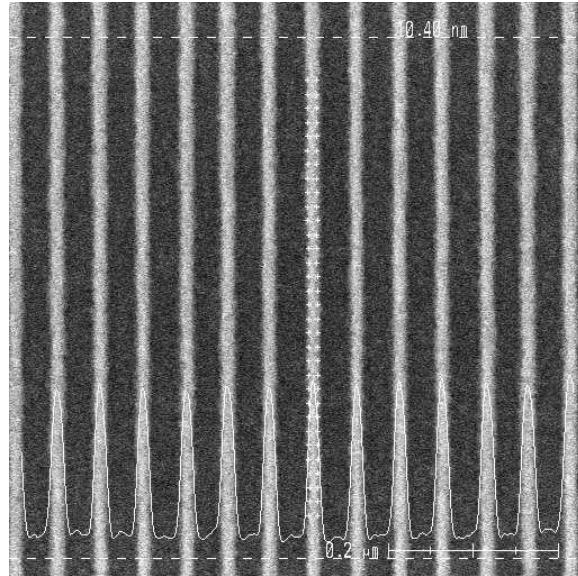
Specs: E-Beam - Laser - Stepper

Parameter	E-Beam SB4050	E-Beam SB255	Stepper FPA3000 i5a	Laser ULTRA	Laser VPG400
Substrates	Up to 450 mm \varnothing	100 - 200 mm \varnothing 6'' x 6''	150 & 200 mm \varnothing	Up to 230 mm x 230 mm	Up to 400 mm x 400 mm
Resolution	30 nm	45 nm	350 nm	500 nm	700 nm
Alignment Accuracy	10 nm (3σ)	25 nm (3σ)	50 nm (3σ)	100 nm (3σ)	200 nm (3σ)
Placement Accuracy	10 nm (3σ)	15 nm	40 nm (3σ)	40 nm (3σ)	100 nm (3σ)
Address Grid	0.6 nm	1 nm	depends on mask	5 nm	10 nm

-  **13:30** **Optimizing chemically amplified photoresist processes in electron beam lithography** **Markus Greul - IMS**
-  **Tomorrow 9:30** **Resolution optimization optical lithography** **Holger Sailer - IMS**

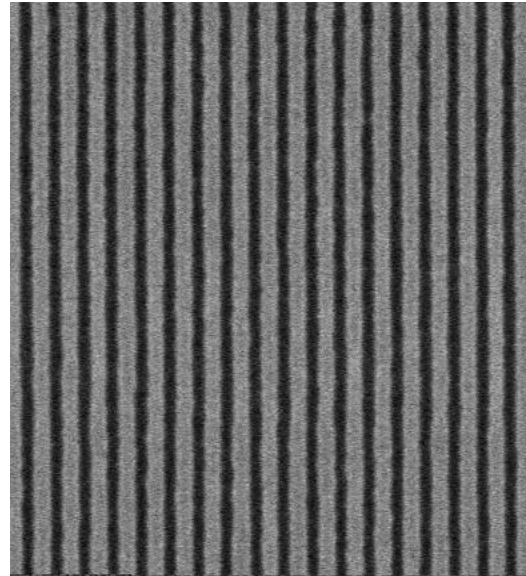
E-Beam SB4050: Resolution

HSQ Line 10.4nm 50nm pitch



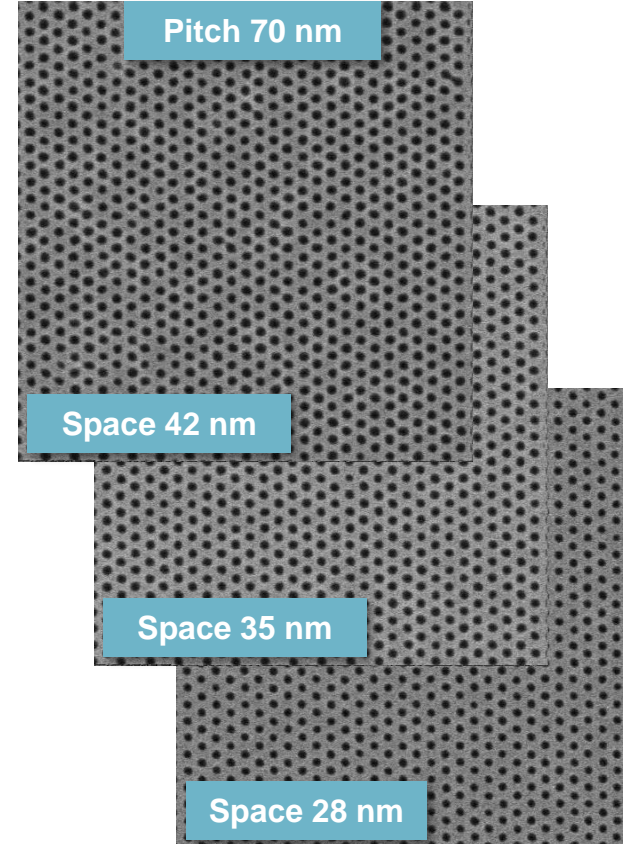
low sensitivity

Pitch 80 nm, Space 40 nm



high sensitivity

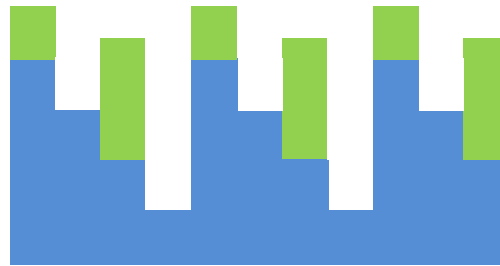
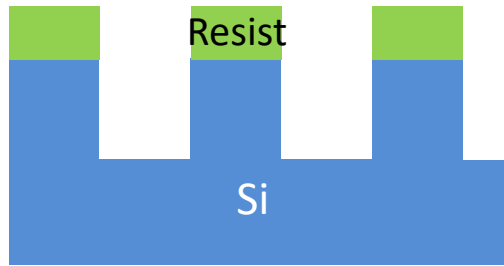
Pitch 70 nm



Space 42 nm

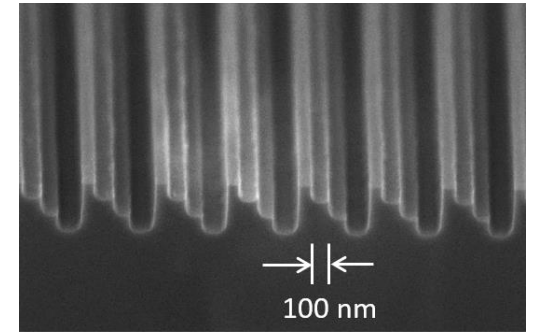
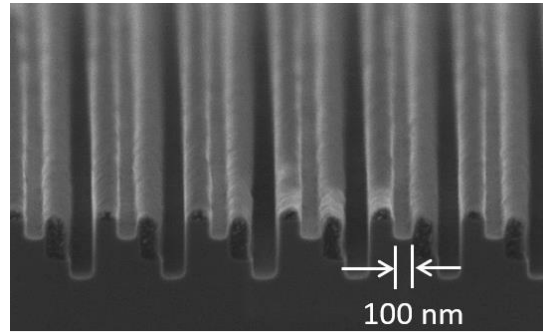
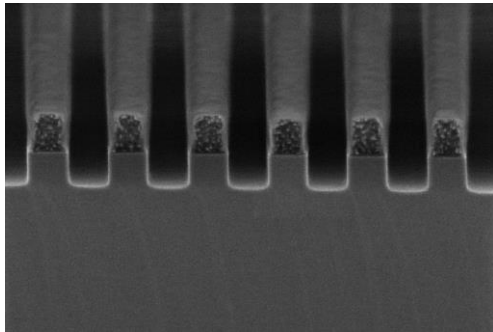
Space 35 nm

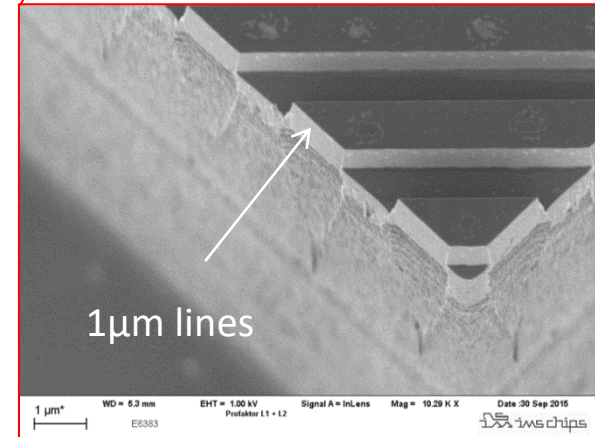
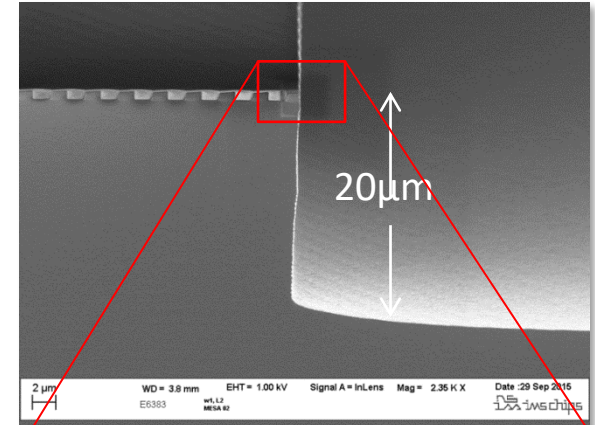
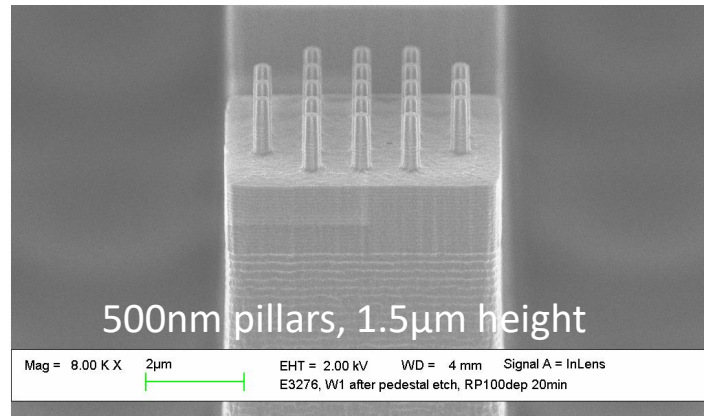
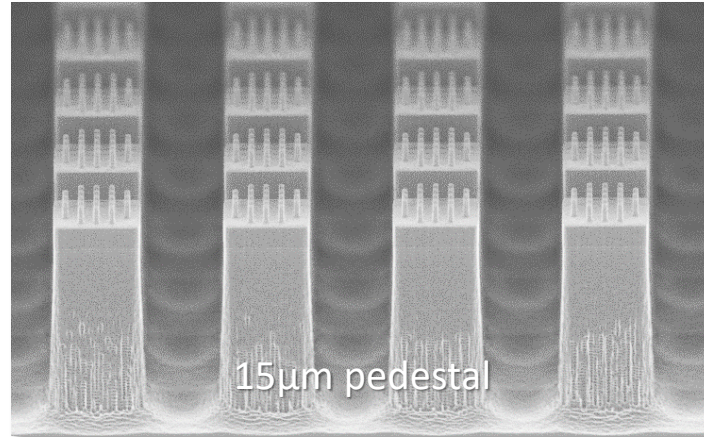
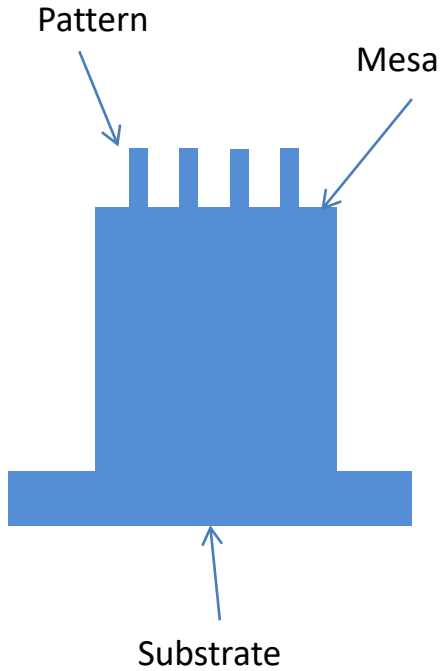
Space 28 nm

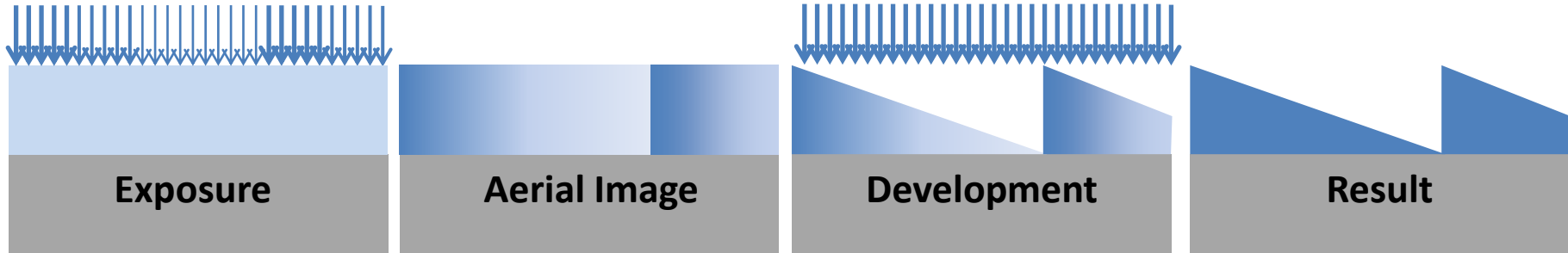
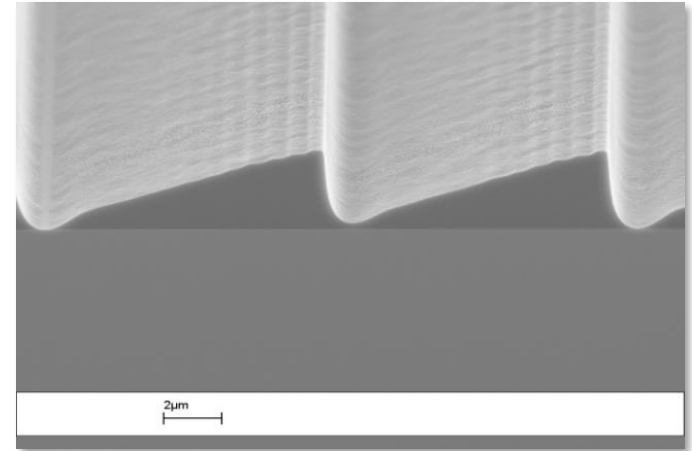
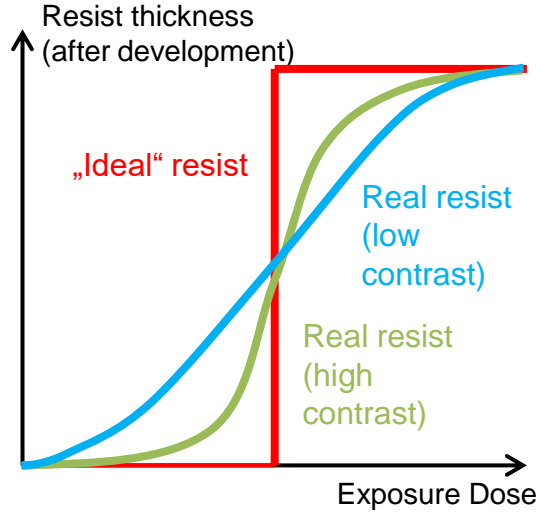


After 1st litho & etch

After 2nd litho & etch

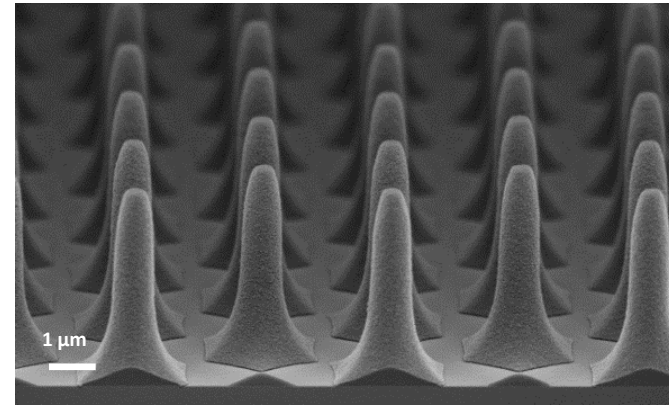
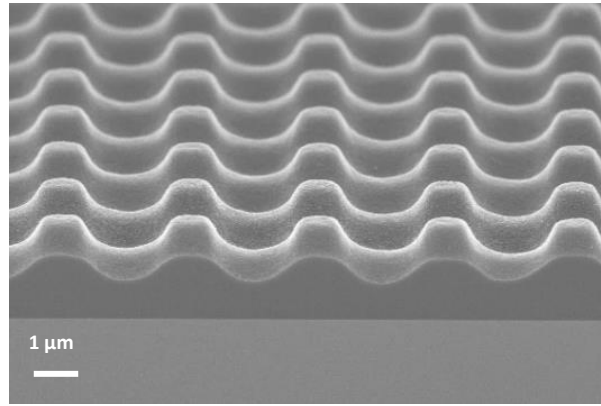
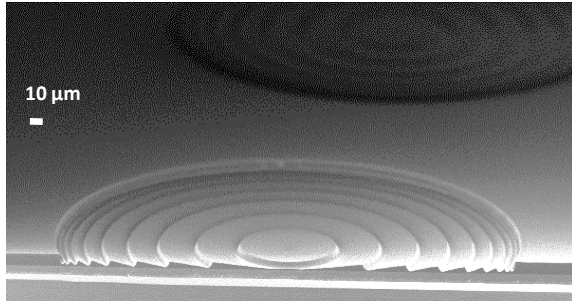




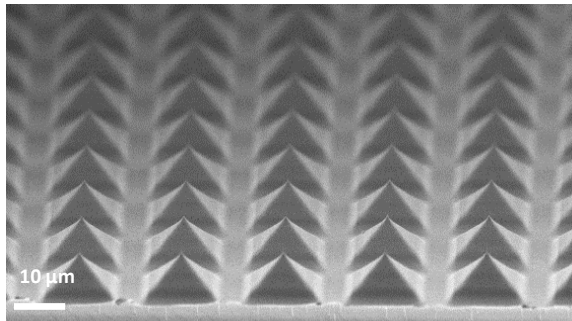


A selection of greyscale images

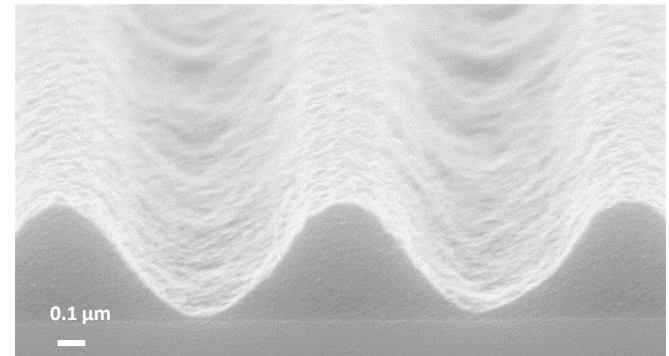
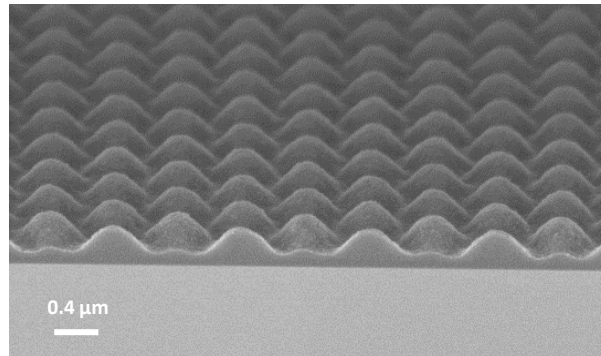
Laser



Laser

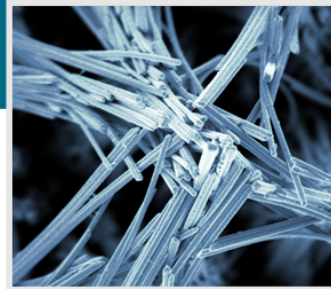


e-beam



21. Workshop Beams & More: 28.11.2024

IMS CHIPS PARTNER FOR ADVANCED NANOPATTERNING



20th Workshop “Beams & More”
November 16th, 2023

HLRS Höchstleistungsrechenzentrum Stuttgart
Nobelstraße 19, Stuttgart



Hartbaum@ims-chips.de

Joachim Burghartz IMS CHIPS Stuttgart, Germany	Welcom	9:30
Julian Hartbaum IMS CHIPS Stuttgart, Germany	IMS CHIPS Update 2023	9:35
Victor Brasch Q.ANT GmbH Stuttgart, Germany	E-beam lithography for integrated quantum optics with lithium niobate on insulator	9:50
Mathias Kaschel IMS CHIPS Stuttgart, Germany	Quantum projects at IMS	10:10
Jorge Blasco Photonicsens Valencia, Spain	Wafer Level Optics for 3D-cameras	10:30
	Coffee Break	10:50
Stefan Fasold, Kevin Edelmann <small>Vistec Electron Beam GmbH, Jena IMS CHIPS, Stuttgart, Germany</small>	E-beam lithography optimization for high quality photonic waveguides	11:20
Uwe Zeitner Fraunhofer IOF Jena, Germany	The potential of e-beam lithography for micro- and nano-optics fabrication on large areas	11:50
Fabien Laulagnet CEA-Leti Grenoble, France	Ebeam Direct Write Lithography: the versatile ally of optical lithography	12:10
Mustapha Chouki IMS Nanofabrication GmbH Brunn am Gebirge, Austria	MBMW-301 and MBMW-100 Flex, the latest revolution in multi-beam mask writing	12:30
	Lunch Break	12:50

Arne Schleunitz micro resist technology Berlin, Germany	Update on photoresists and NIL polymers for advanced micro- and nanopatterning techniques	14:20
P. Schuster/T. Achleitner EVGroup St. Florian am Inn, Austria	NIL for advanced packaging	14:40
Marc Verschuuren SCIL Nanosprint Solutions Eindhoven, The Netherlands	Wafer based NIL for direct replication of inorganic functional optical materials	15:00
Stefan Schrittwieser <small>AIT Austrian Institute of Technology GmbH Vienna, Austria</small>	Nanoimprint lithography for the fabrication of multifunctional nanoparticles for biomedical applications	15:20
	Coffee Break	15:40
Philip Müller Carl Zeiss SMT Oberkochen, Germany	High-NA EUV – the future that is already here	16:10
Jean-Michel Asfour Diopic GmbH Weinheim, Germany	Computer Generated Holograms with continuous phase relief structure for beam shaping of Excimer lasers for medical applications	16:30
Sven Bauerdick GenSys GmbH Taufkirchen, Germany	SEM-based metrology for micro and nano patterns	16:50
Julian Hartbaum IMS CHIPS Stuttgart, Germany	Closing remarks	17:10
	Joint Dinner at relexa Waldhotel Schatten	18:30